TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

# 2SC4738FT

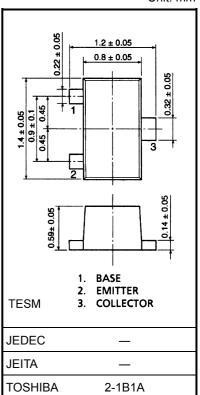
Audio Frequency General Purpose Amplifier Applications

Unit: mm

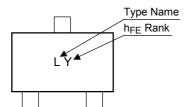
- High Voltage:  $V_{CEO} = 50 \text{ V}$
- High Current: I<sub>C</sub> = 150 mA (max)
- High hFE: hFE = 120 to 400
- Excellent hFE Linearity
  - $: h_{FE} (I_C = 0.1 \text{ mA})/h_{FE} (I_C = 2 \text{ mA}) = 0.95 (typ.)$
- Complementary to 2SA1832FT

#### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	60	V
Collector-emitter voltage	V <sub>CEO</sub>	50	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	Ι <sub>C</sub>	150	mA
Base current	Ι <sub>Β</sub>	30	mA
Collector power dissipation	P <sub>C</sub>	100	mW
Junction temperature	Тј	125	°C
Storage temperature range	T <sub>stg</sub>	-55 to 125	°C



#### Marking



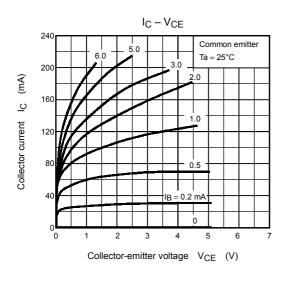
### Electrical Characteristics (Ta = 25°C)

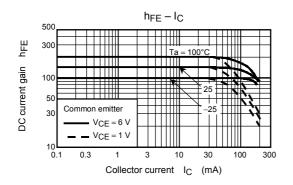
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 60 V, I_{E} = 0$	_	_	0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = 5 V, I_C = 0$			0.1	μA
DC current gain	h <sub>FE</sub> (Note)	$V_{CE} = 6 V, I_C = 2 mA$	120		400	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	$I_{C} = 100 \text{ mA}, I_{B} = 10 \text{ mA}$		0.1	0.25	V
Transition frequency	f <sub>T</sub>	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 1 \text{ mA}$	80	_	_	MHz
Collector output capacitance	Cob	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	2.0	3.5	pF

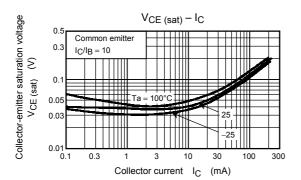
Note: h<sub>FE</sub> Classification Y (Y): 120 to 240, GR (G): 200 to 400

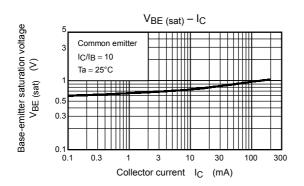
() Marking symbol

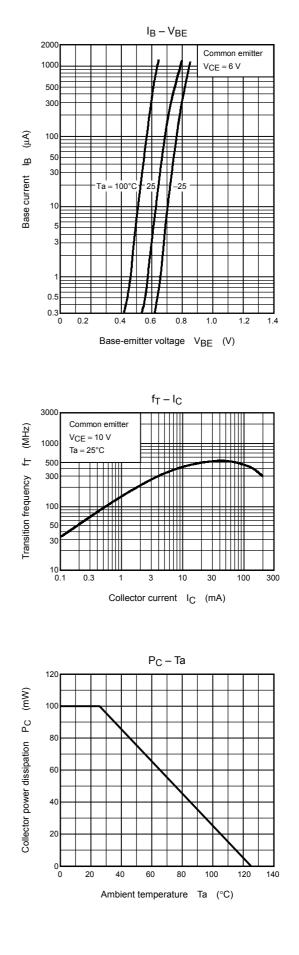
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